

# **Hierarchical architectures of Co<sub>3</sub>O<sub>4</sub> ultrafine nanowires grown on Co<sub>3</sub>O<sub>4</sub> nanowires with fascinating electrochemical performance**

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## Part I: Calculations

The specific capacitance (C) of the electrode was calculated from the discharge curves using the following formula<sup>1</sup>:

$$C = \frac{I \times \Delta t}{m \times \Delta V}$$

where  $I$  (A),  $\Delta t$  (s),  $m$  (g), and  $\Delta V$  (V) are the discharge current, discharge time consumed in the potential range of  $\Delta V$ , mass of the active materials, and the potential windows, respectively.

The energy density (E) and power density (P) are calculated from the discharge curves using the following formula:

$$E = \text{Error!} \times C \times \Delta V^2$$
$$P = \frac{E}{\Delta t}$$

1. J. Yan, E. Khoo, A. Sumboja and P. S. Lee. *ACS Nano*, 2010, **4**, 4247.

## Part II: Supplementary Figures

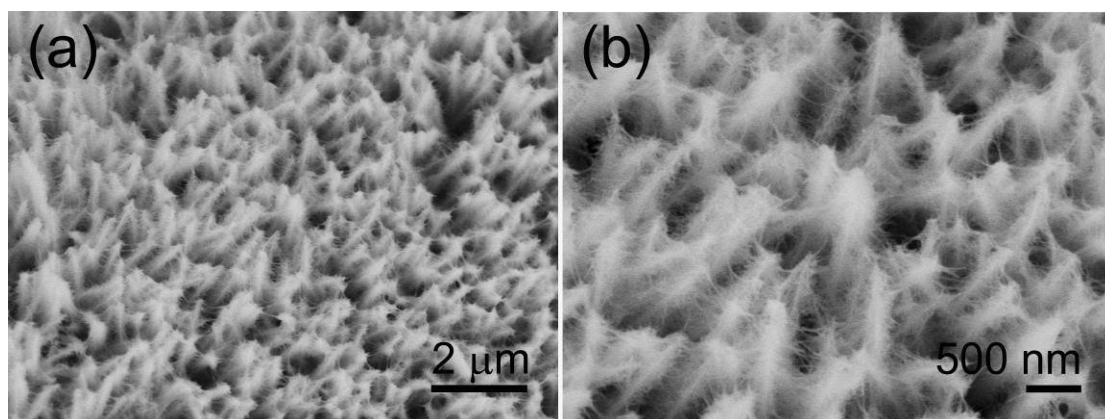


Fig S1 Low- and high- magnification SEM images of the Co-based intermediate.

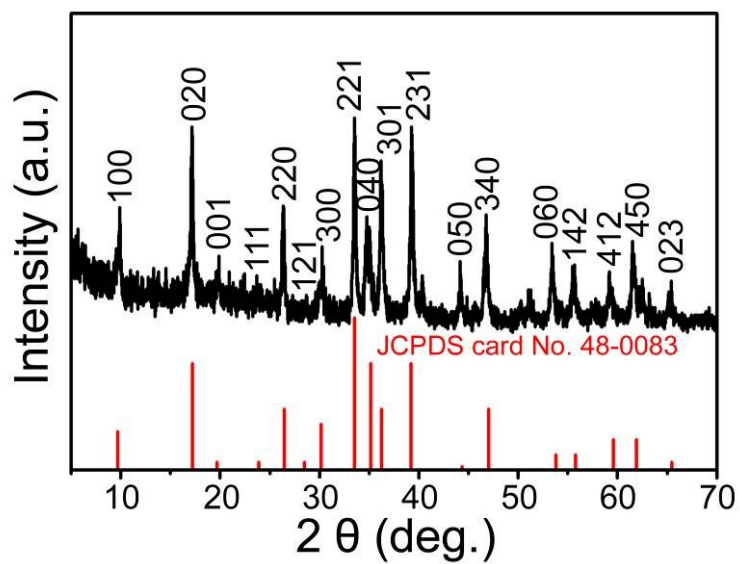


Fig S2 XRD patterns of the as-prepared Co-based intermediate.

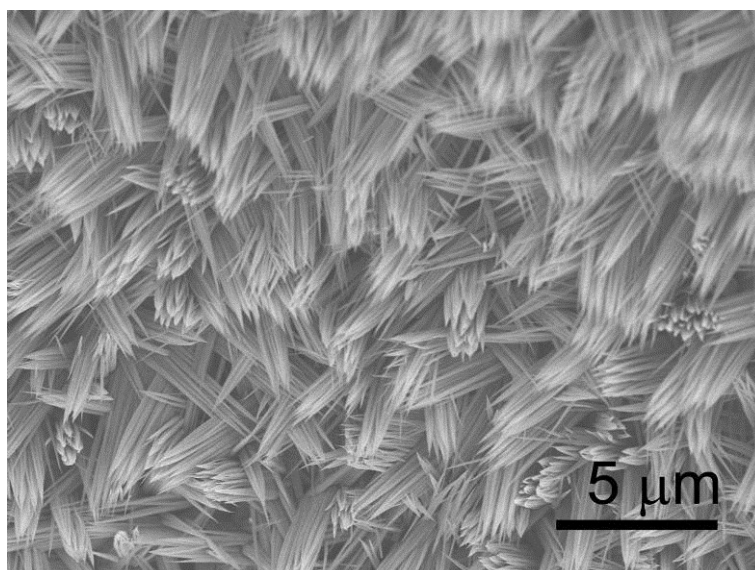


Fig S3 SEM image of the conventional  $\text{Co}_3\text{O}_4$  nanowires.

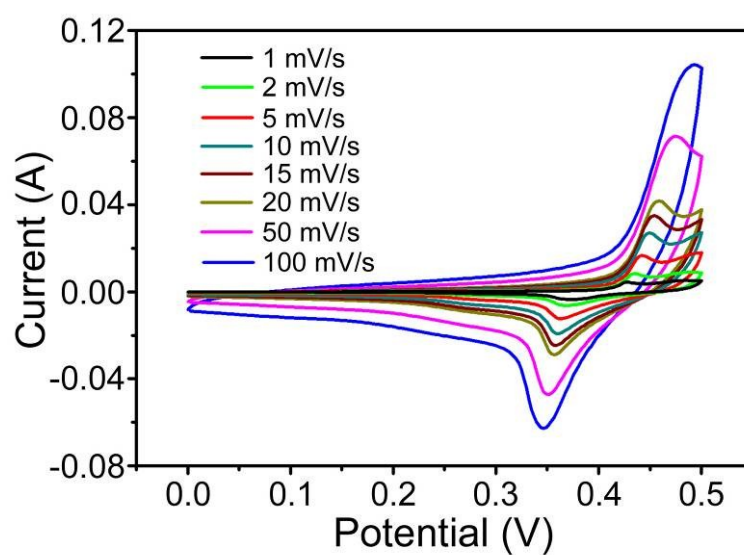


Fig S4 CV curves of the conventional  $\text{Co}_3\text{O}_4$  nanowires at different scan rates, respectively.

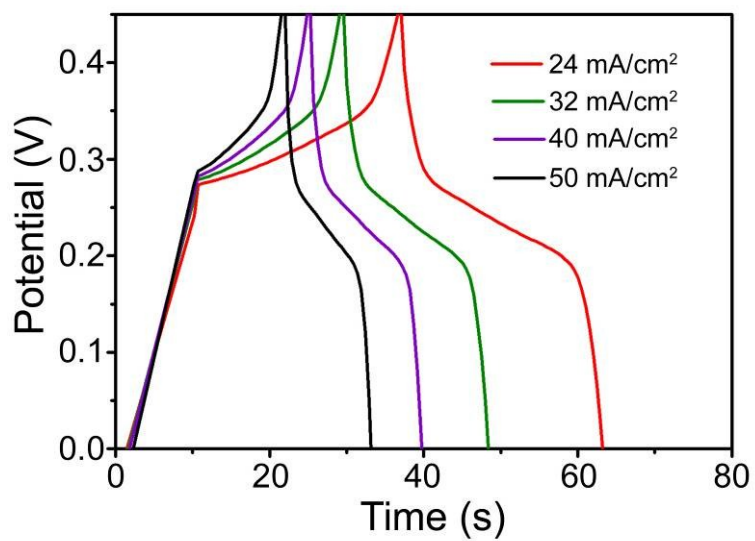


Fig S5 Galvanostatic charge-discharge curves of the Co<sub>3</sub>O<sub>4</sub> nanowires@nanowires at different high current densities, respectively.

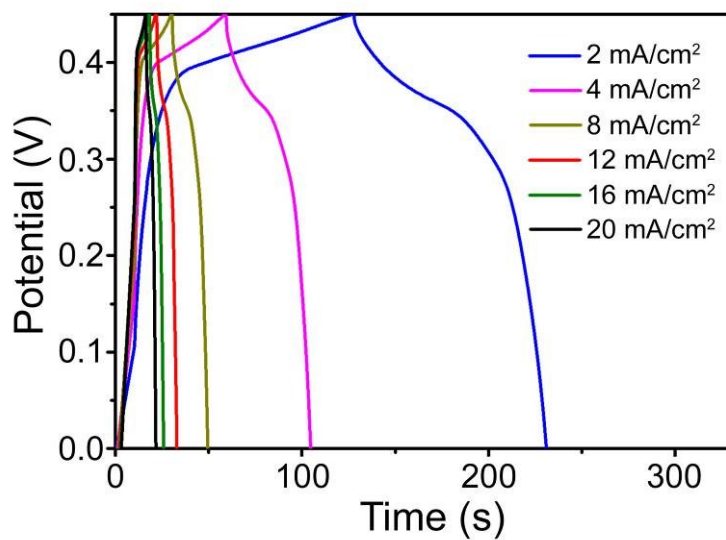


Fig S6 Galvanostatic charge-discharge curves of the conventional Co<sub>3</sub>O<sub>4</sub> nanowires at different current densities, respectively.

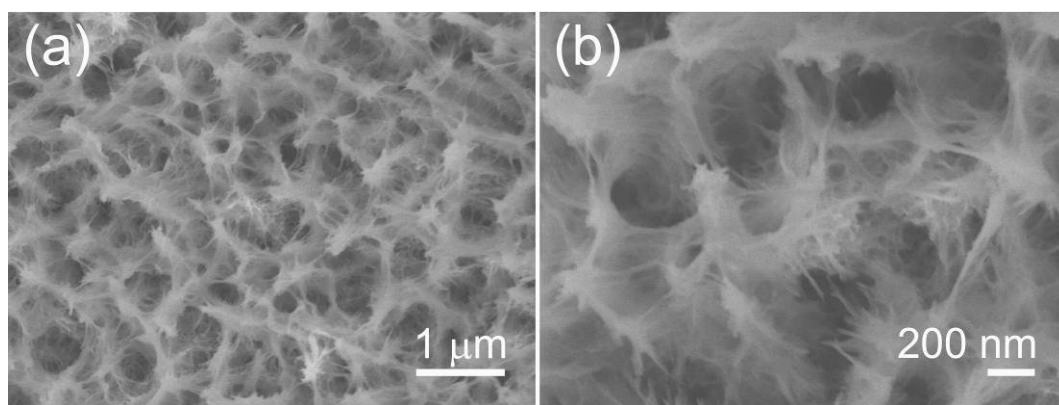


Fig. S7 Different magnification SEM images of the hierarchical  $\text{Co}_3\text{O}_4$  nanowires@nanowires on Ni foam after 10000 cycle CV test.

Table S1 A comparison of the capacitance for the Co<sub>3</sub>O<sub>4</sub> nanowires@ultrafine nanowire electrode material with other reported Co<sub>3</sub>O<sub>4</sub> materials based electrodes in previous literatures.

Electrode Materials	Specific Capacitance	Rate Capability	Ref.
Co <sub>3</sub> O <sub>4</sub> nanowires@ultrafine nanowires	1640 F g <sup>-1</sup> at 2mA cm <sup>-2</sup> (1640 F g <sup>-1</sup> at 1.7 A g <sup>-1</sup> )	66% retention from 2 to 50 mA cm <sup>-2</sup>	This work
Co <sub>3</sub> O <sub>4</sub> nanoparticles	519 F g <sup>-1</sup> at 0.5 mA cm <sup>-2</sup>	25.8% retention from 0.5 to 10 mA cm <sup>-2</sup>	18
Dendrite-like Co <sub>3</sub> O <sub>4</sub> nanostructures	207.8 F g <sup>-1</sup> at 0.5 A g <sup>-1</sup>	36.1% retention from 0.5 to 6 A g <sup>-1</sup>	19
Mesoporous Co <sub>3</sub> O <sub>4</sub> nanocubes	350 F g <sup>-1</sup> at 0.2 A g <sup>-1</sup>	45.7% retention from 0.2 to 2 A g <sup>-1</sup>	20
Hollow Co <sub>3</sub> O <sub>4</sub> boxes	278 F g <sup>-1</sup> at 0.5 A g <sup>-1</sup>	63.3% retention from 0.5 to 5 A g <sup>-1</sup>	37
Co <sub>3</sub> O <sub>4</sub> nanowires	1217.4 F g <sup>-1</sup> at 0.7 A g <sup>-1</sup>	57.5% retention from 0.7 to 20 A g <sup>-1</sup>	38
Flower-like Co <sub>3</sub> O <sub>4</sub> microspheres	541.9 F g <sup>-1</sup> at 1 A g <sup>-1</sup>	54% retention from 0.7 to 20 A g <sup>-1</sup>	39
Nanonet-like Co <sub>3</sub> O <sub>4</sub>	1084 F g <sup>-1</sup> at 5 mA cm <sup>-2</sup>	62.1% retention from 5 to 100 mA cm <sup>-2</sup>	40
Co <sub>3</sub> O <sub>4</sub> @MnO <sub>2</sub> nanoflakes	675.9 F g <sup>-1</sup> at 1 A g <sup>-1</sup>	26.8% retention from 1 to 10 A g <sup>-1</sup>	41
Co <sub>3</sub> O <sub>4</sub> @MnO <sub>2</sub> nanoconch arrays	1183.6 F g <sup>-1</sup> at 1 A g <sup>-1</sup>	51.6% retention from 1 to 10 A g <sup>-1</sup>	42
Co <sub>3</sub> O <sub>4</sub> nanowire@MnO <sub>2</sub> ultrathin nanosheet	480 F g <sup>-1</sup> at 2.67 A g <sup>-1</sup>	55.6% retention from 2.67 to 29.8 A g <sup>-1</sup>	43
Hybrid NiO/Co <sub>3</sub> O <sub>4</sub> architectures	193 F g <sup>-1</sup> at 3 A g <sup>-1</sup>	60.1% retention from 3 to 8 A g <sup>-1</sup>	44
ZnO@Co <sub>3</sub> O <sub>4</sub> core/shell heterostructures	857.7 F g <sup>-1</sup> at 2 mA cm <sup>-2</sup>	63.4% retention from 2 to 20 mA cm <sup>-2</sup>	45
Co <sub>3</sub> O <sub>4</sub> /RGO composites	518.8 F g <sup>-1</sup> at 0.5 A g <sup>-1</sup>	47.6% retention from 0.5 to 10 A g <sup>-1</sup>	46
Co <sub>3</sub> O <sub>4</sub> /Carbon composites	400 F g <sup>-1</sup> at 0.5 A g <sup>-1</sup>	37.5% retention from 0.5 to 5 A g <sup>-1</sup>	47
Co <sub>3</sub> O <sub>4</sub> nanoplates/grapheme nanosheets	703.4 F g <sup>-1</sup> at 0.625 A g <sup>-1</sup>	37.5% retention from 0.625 to 12.5 A g <sup>-1</sup>	48